

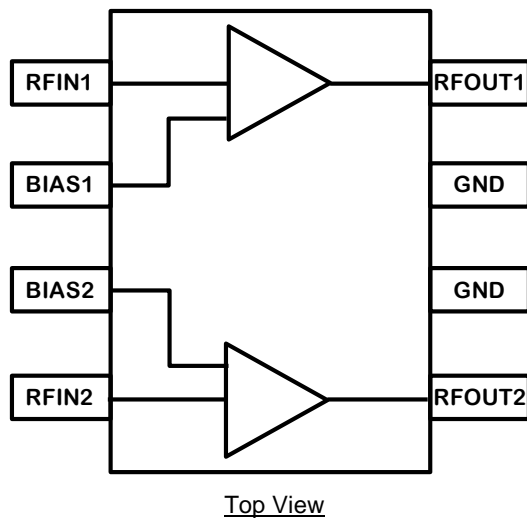
Product Overview

The QPB2318 is an HBT RF balanced amplifier IC operating as a return path amplifier capable of supporting DOCSIS 3.1 applications. This IC is designed to provide a low noise, high gain option for 5-210MHz interface using an 8V power supply to provide lower overall power dissipation. The QPB2318 can also be used in 5V and single ended applications with reduced linearity requirements. The QPB2318 is packaged in a convenient SOIC8 package and features an externally adjustable bias control.



Package: SOIC-8 with Exposed Pad

Functional Block Diagram



Key Features

- 5MHz to 210MHz Operation
- 8V and 5V Operation
- Gain; 15.5dB Typical
- Noise Figure 3.8dB Typical
- Adjustable Bias Using External Resistors
- SOIC-8 Exposed Pad

Applications

- Head End CMTS Equipment
- Post Amp for Return Path Optical Receivers
- DOCSIS 3.1 Optical Nodes
- Residential Amplifiers and Splitters

Ordering Information

Part No.	Description
QPB2318SQ	Sample bag with 25 pieces
QPB2318SR	7" Reel with 100 pieces
QPB2318TR13	13" Reel with 2500 pieces
QPB2318PCK	5 – 210 MHz PCBA with 5 pc sample bag



Absolute Maximum Ratings

Parameter	Rating
Supply Voltage (V_{DD})	+10V
Supply Current (I_{DD})	350mA
Maximum CW Input Power for $V_{DD}=8V$	+18dBm
Operating Temperature Range	-40 to +85 °C
Storage Temperature Range	-65 to +150 °C
Maximum Junction Temperature	+150 °C

Exceeding any one or a combination of the Absolute Maximum Rating conditions may cause permanent damage to the device. Extended application of Absolute Maximum Rating conditions to the device may reduce device reliability.

Electrical Specifications – Push-Pull Configuration, 8V

Parameter	Condition ⁽¹⁾	Min	Typ	Max	Unit
Supply Voltage (V_{DD})			8		V
Supply Current (I_{DD})			235		mA
Frequency Range		5		210	MHz
Gain	Full Band		15.5		dB
Gain Flatness			±0.2		dB
Gain Tilt	Gain(210MHz) - Gain(5MHz)		0.2		dB
Input Return Loss	Full Band		18		dB
Output Return Loss	Full Band		25		dB
Reverse Isolation	Full Band		20		dB
Noise Figure	Includes balun loss		3.8		dB
DTO	f1=13MHz, f2=19MHz 61dBmV per tone		72		-dBc
DSO	f1=13MHz, f2=19MHz 61dBmV per tone		82		-dBc
ACLR	Pout = 64dBmV, 5-195MHz OFDM w/ 9.6MHz exclusion band.		63		dB
OIP2	12dBm/tone, F1 = 113MHz, F2 = 119MHz		95		dBm
OIP3	12dBm/tone, F1 = 113MHz, F2 = 119MHz		48		dBm
Output P1dB	Full Band		26.2		dBm
Thermal Resistance	Θ_{JC}		12		°C/W

Notes:

1. Typical performance at these conditions: Temp = +25°C, V_{DD} = +8V, 75Ω system

Electrical Specifications – Single Ended, 8V (50Ω)

Parameter	Condition ⁽¹⁾	Min	Typ	Max	Unit
Supply Current (I_{DD})			115		mA
Gain			15.4		dB
OIP2L	9dBm/tone, F1 = 113MHz, F2 = 123MHz		59.3		dBm
OIP2H	9dBm/tone, F1 = 113MHz, F2 = 123MHz		60.1		dBm
OIP3	9dBm/tone, F1 = 113MHz, F2 = 123MHz		44.4		dBm

Notes:

1. Typical performance at these conditions: Singled ended configuration, Temp = +25°C, V_{DD} = +8V, **50Ω system**
2. 50ohm data represents factory test conditions

Electrical Specifications – Push-Pull Configuration, 5V

Parameter	Condition ⁽¹⁾	Min	Typ	Max	Unit
Supply Voltage (V_{DD})			5		V
Supply Current (I_{DD})			110		mA
Frequency Range		5		210	MHz
Gain	Full Band		15.2		dB
Gain Flatness			±0.2		dB
Gain Tilt	Gain(210MHz) - Gain(5MHz)		0.15		dB
Input Return Loss	Full Band		19		dB
Output Return Loss	Full Band		26		dB
Reverse Isolation	Full Band		20		dB
Noise Figure	Includes balun loss		3.8		dB
DTO	f1=13MHz, f2=19MHz 53dBmV per tone		67		-dBc
DSO	f1=13MHz, f2=19MHz 53dBmV per tone		79		-dBc
ACLR	Pout = 56dBmV, 5-195MHz OFDM w/ 9.6MHz exclusion band.		64		dB
OIP2	4dBm/tone, F1 = 113MHz, F2 = 119MHz		83		dBm
OIP3	4dBm/tone, F1 = 113MHz, F2 = 119MHz		38		dBm
Output P1dB	Full Band		21		dBm

Notes:

1. Typical performance at these conditions: Temp = +25°C, V_{DD} = +5V, 75Ω system



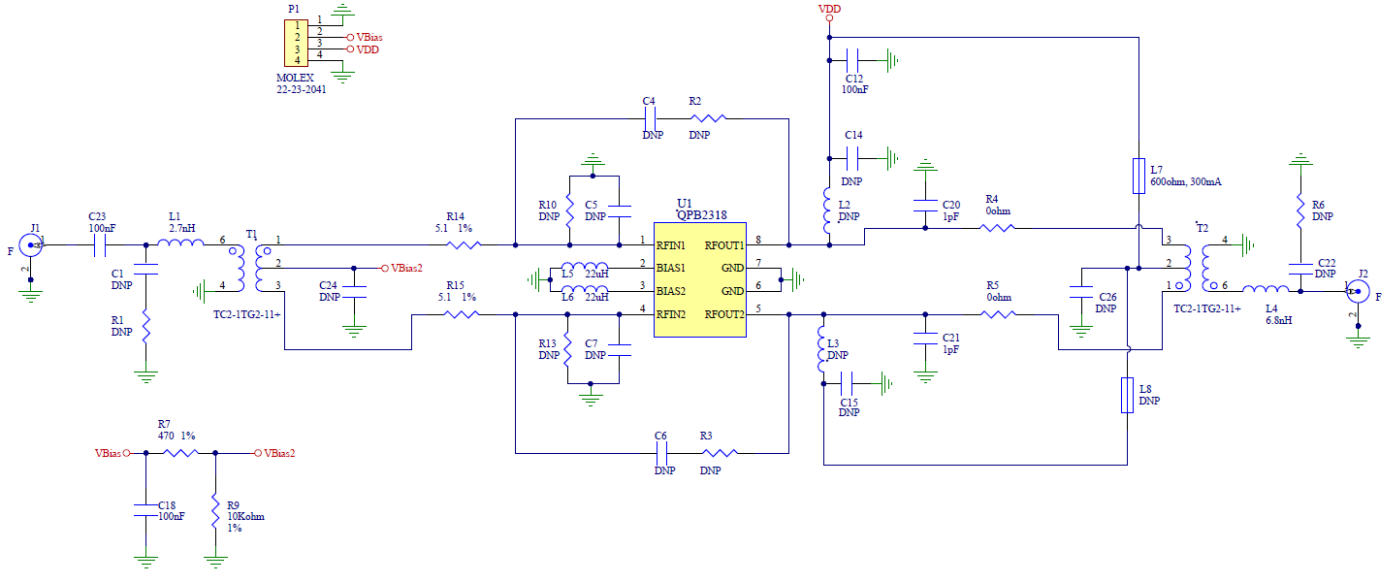
Electrical Specifications – Single Ended Configuration, 5V

Parameter	Condition ⁽¹⁾	Min	Typ	Max	Unit
Supply Voltage (V_{DD})			5		V
Supply Current (I_{DD})			55		mA
Frequency Range		5		210	MHz
Gain	Full Band		16.5		dB
Gain Flatness			± 0.2		dB
Gain Tilt	Gain(210MHz) - Gain(5MHz)		0.3		dB
Input Return Loss	Full Band		21		dB
Output Return Loss	Full Band		19		dB
Reverse Isolation	Full Band		19		dB
Noise Figure	Full bandwidth		3.7		dB
DTO	f1=13MHz, f2=19MHz 46dBmV per tone		77		-dBc
DSO	f1=13MHz, f2=19MHz 46dBmV per tone		53		-dBc
ACLR	Pout = 49dBmV, 5-195MHz OFDM w/ 9.6MHz exclusion band.		61		dB
OIP2	-3dBm/tone, F1 = 113MHz, F2 = 119MHz		50		dBm
OIP3	-3dBm/tone, F1 = 113MHz, F2 = 119MHz		36		dBm
Output P1dB	Full Band		18.7		dBm

Notes:

1. Typical performance at these conditions: Temp = +25°C, V_{DD} = +5V applied to single amplifier path, 75Ω system

Evaluation Board Schematic 5-210MHz





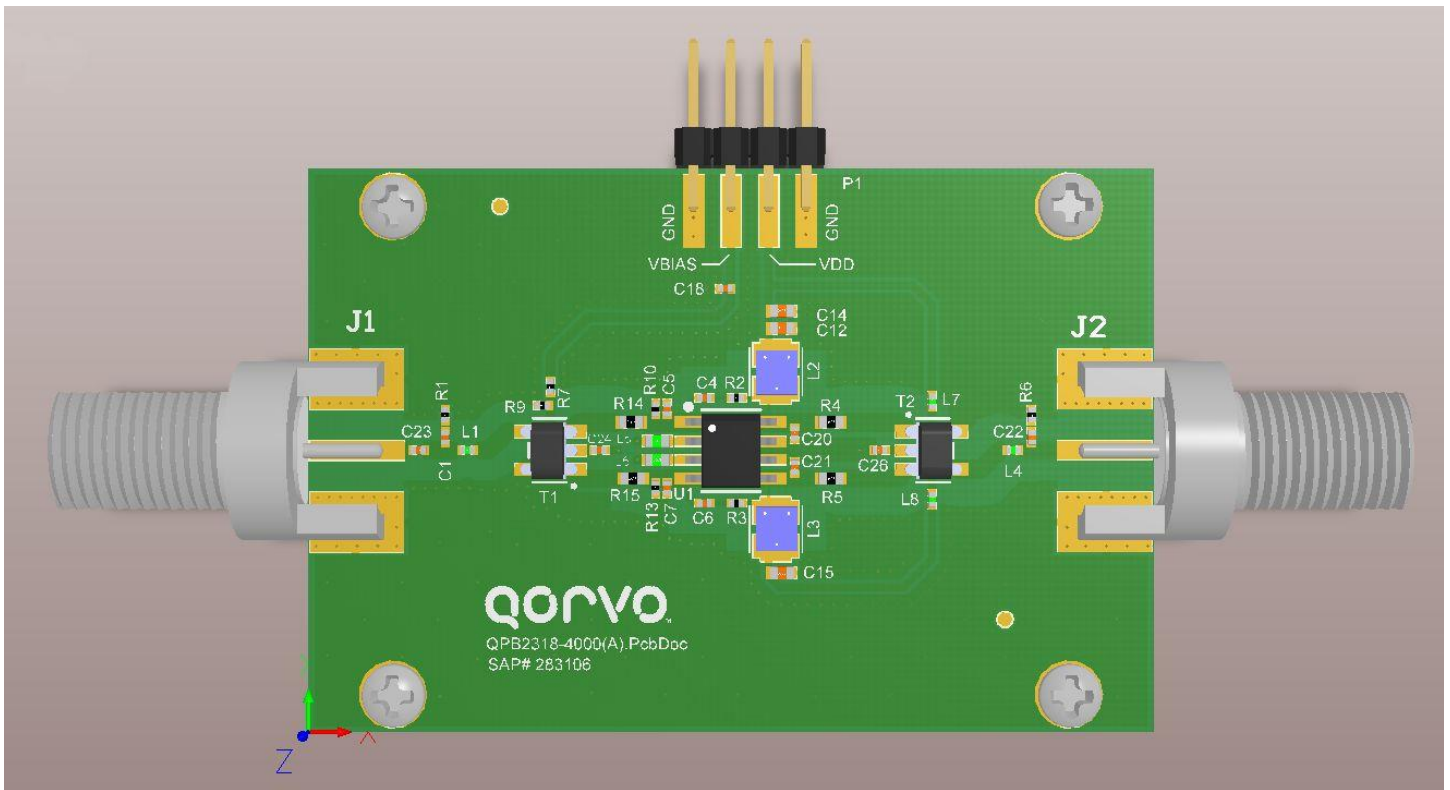
QPB2318

15 dB Balanced Return Path Amplifier 5 – 210 MHz

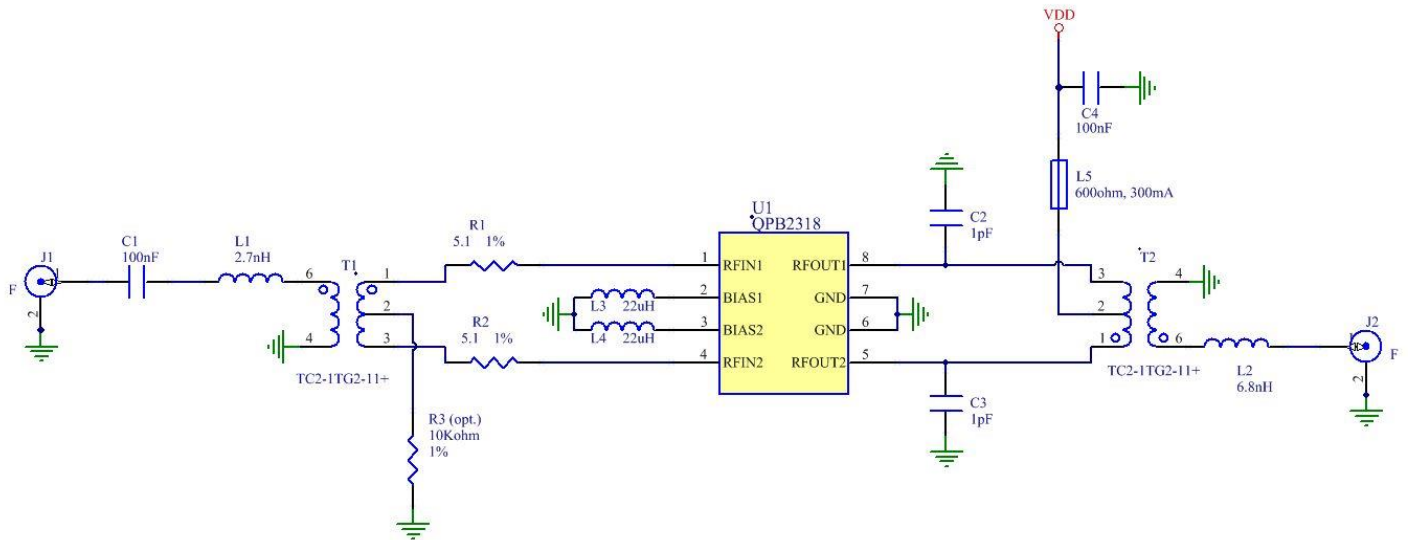
Evaluation Board Bill of Materials

Designator	Description	Manufacturer	Part Number
PCB	QPB2318-4000	DDI	QPB2318-4000(A)
C12, C18, C23	CAP, 0.1uF, 10%, 16V, X7R, 0402	Murata Electronics	GRM155R71C104KA88D
C20, C21	1.0PF, .1PF, 50, NPO, 0402, LF LEAD FREE	Murata Electronics	GRM1555C1H1R0BZ01D
J1, J2	CONN, F FEM EDGE MOUNT, 75 OHMS, 0.068"	Millimeter Wave Technologies, LLC	MW-846-C-DD-75
L1	IND, 2.7nH, +/-0.3nH, M/L, 0402	Murata Electronics	LQG15HS2N7S02D
L4	IND, 6.8nH, 5%, M/L, 0402	Murata Electronics	LQG15HN6N8J02D
L5, L6	IND, 22uH, 20%, 190mA, M/L, 0603	TDK	MLZ1608N220LT000
L7	FER, BEAD, 600 OHM, 300mA, 0402	Murata	BLM15HG601SN
P1	CONN, HDR, ST, FRCTN LOCK, 4-PIN	MOLEX	22-23-2041
R14, R15	RES, 5.1 OHM, 1%, 1/10W, 0402	Kamaya, Inc	RMC1/16SK5R10FTH
R4, R5	JMPR, 0 OHM, 0402	Panasonic Industrial Devices Sales	ERJ-2GE0R00
R7	Res, 470R /1%/0402/TK100/Chip	Kamaya, Inc	RMC1/16SK4700FTH
R9	RES, 10K, 1%, 1/16W, 0402	Panasonic Industrial Devices Sales	ERJ-2RKF1002X
T1, T2	XFMR, 3-300MHz, 50 OHM, 250mW, AT224-3	Minicircuits	TC2-1TG2-11+
U1	15dB High-Linearity Push-Pull MMIC	Qorvo	QPB2318
C1, C4, C5, C6, C7, C14, C15, C22, C24, C26, L2, L3, L8, R1, R2, R3, R6, R10, R13	DNP	N/A	N/A
HS1	Heat Sink 1.5 x 2	Shenzhen Minxingda Automation Equip	
S1, S2, S3, S4	Screw, 2-56x3/16:, Socket Head	McMaster-Carr Supply Co.	92196A076

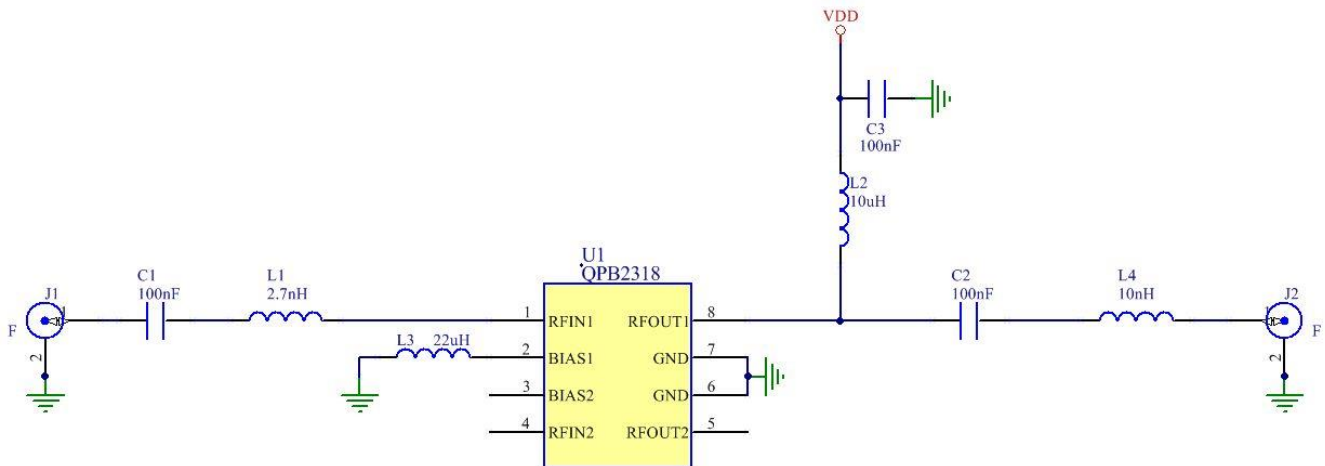
Evaluation Board Assembly Drawing



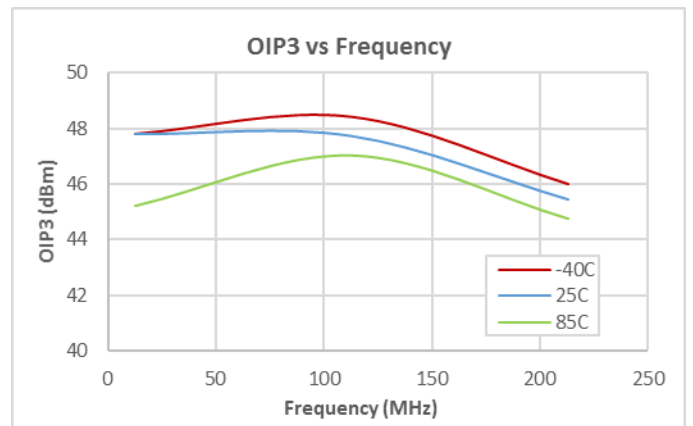
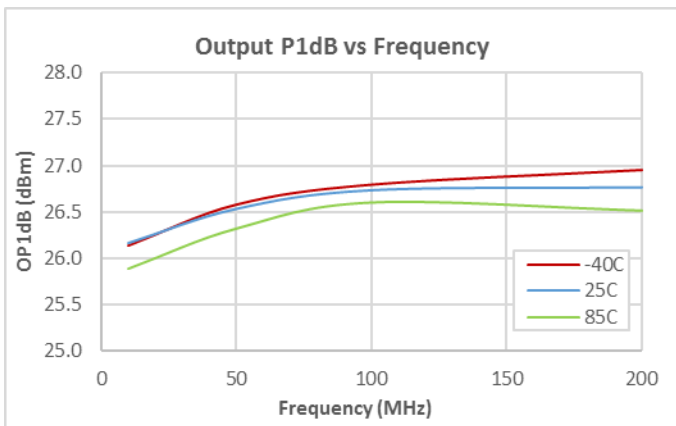
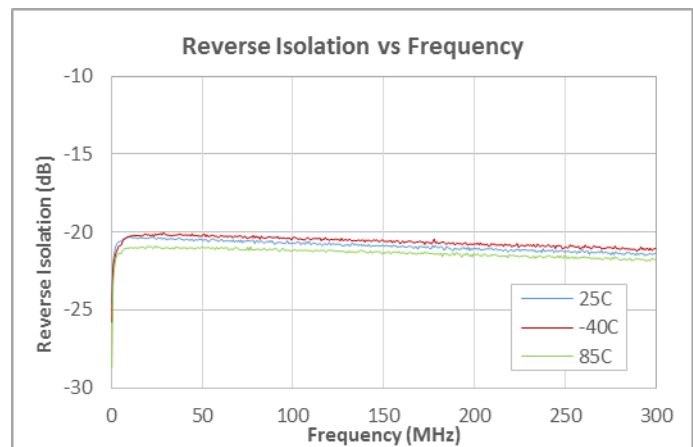
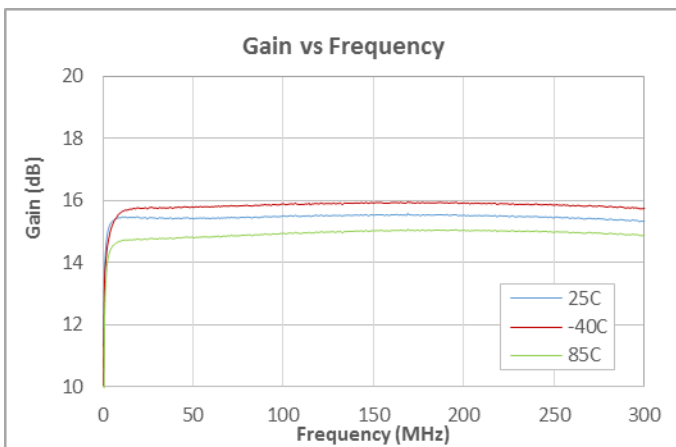
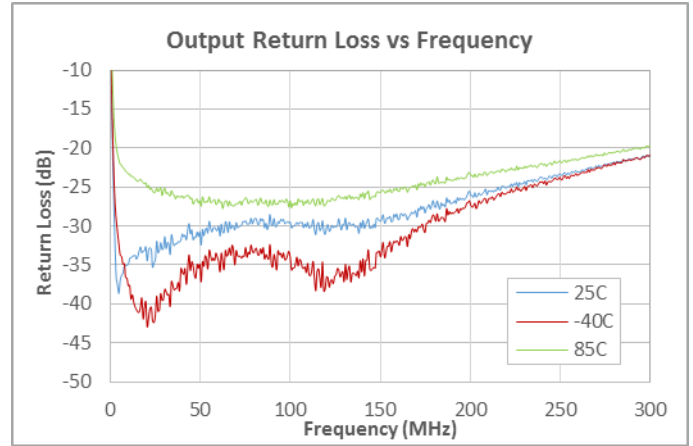
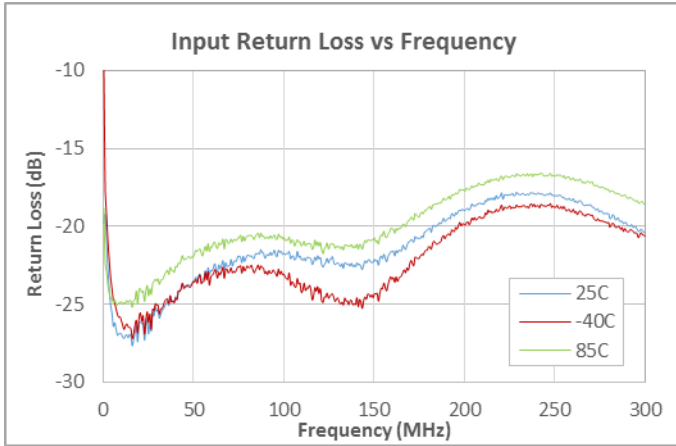
Typical Application Schematic – Push-Pull Configuration



Typical Application Schematic – Single Ended Configuration



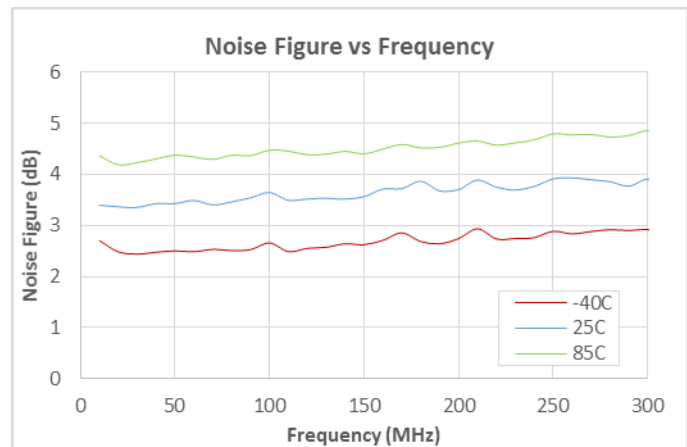
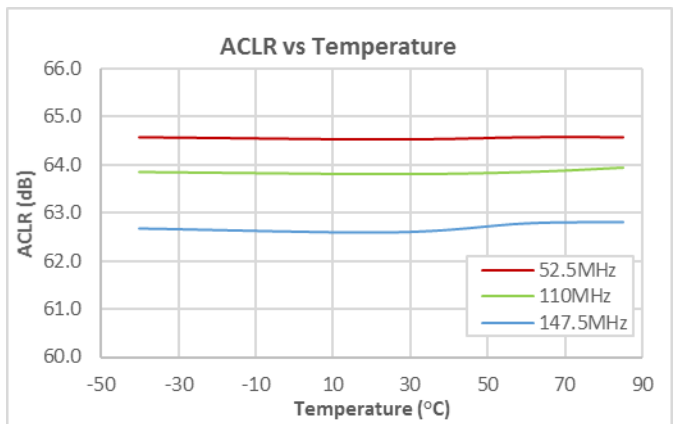
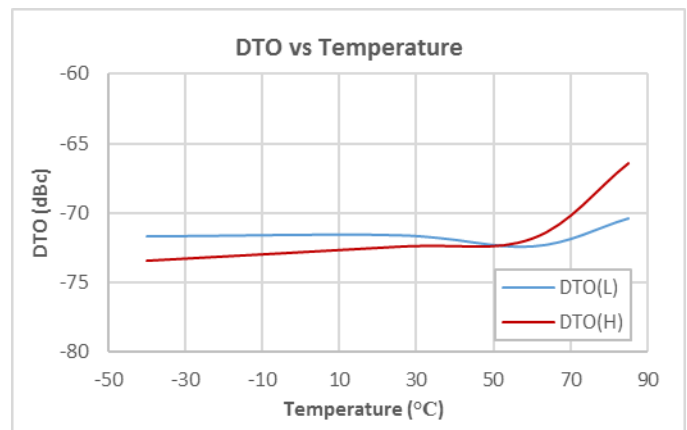
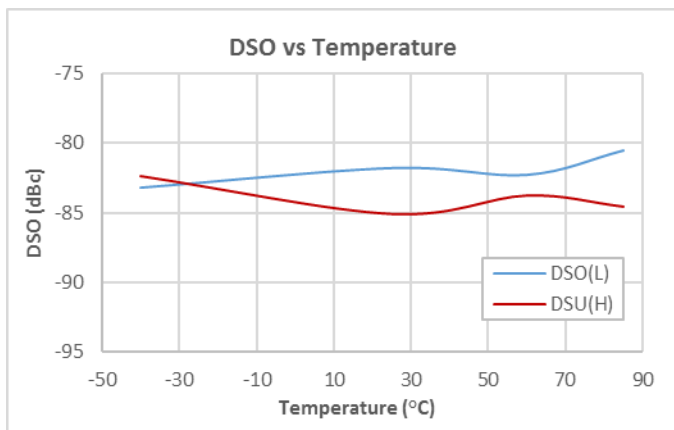
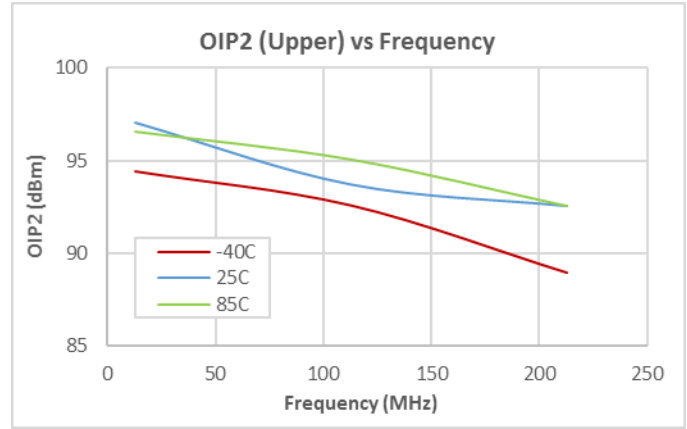
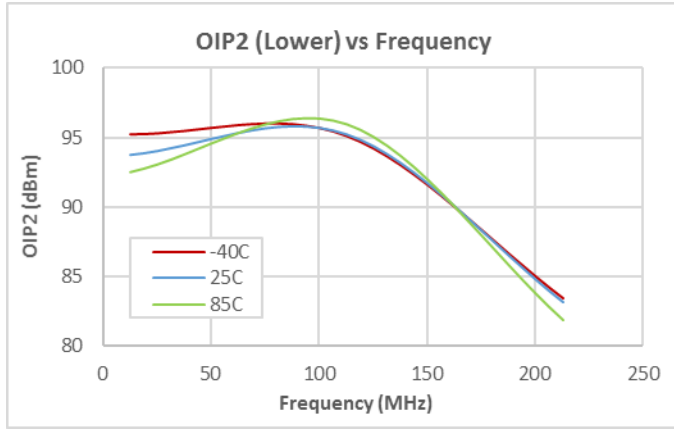
Performance Data – Push-Pull Configuration, 8V



Notes:

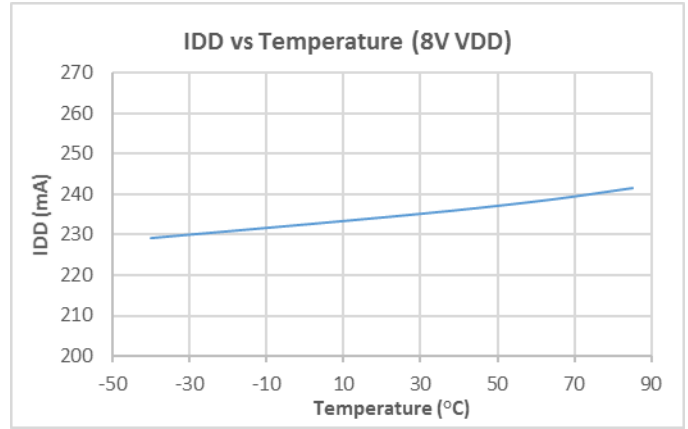
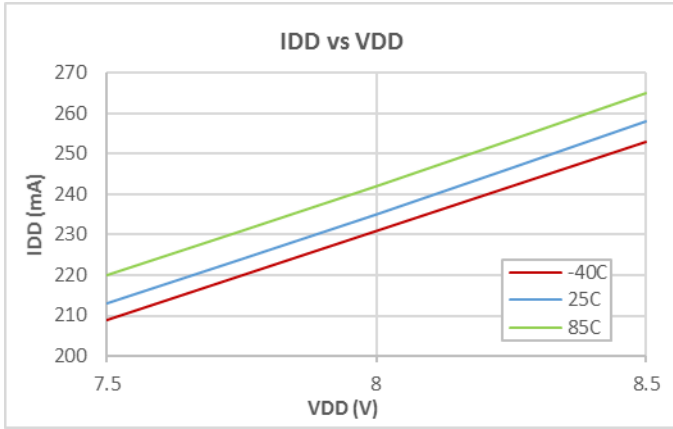
- (1) OIP3: 12dBm/tone, F1 = 113MHz, F2 = 119MHz

Performance Data – Push-Pull Configuration, 8V

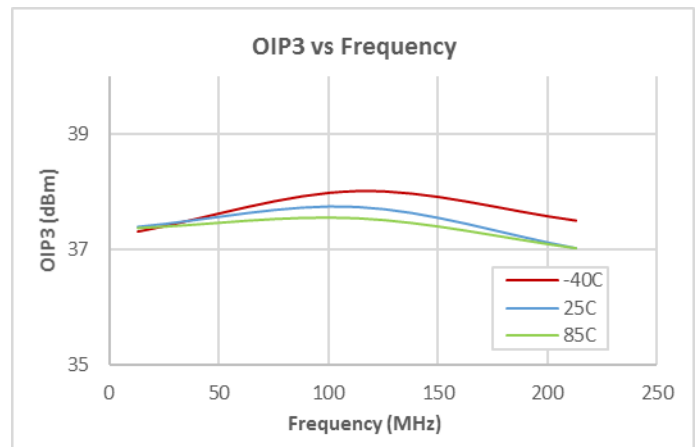
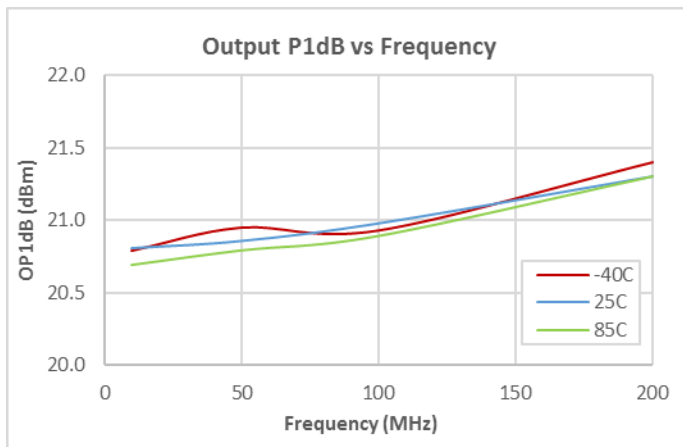
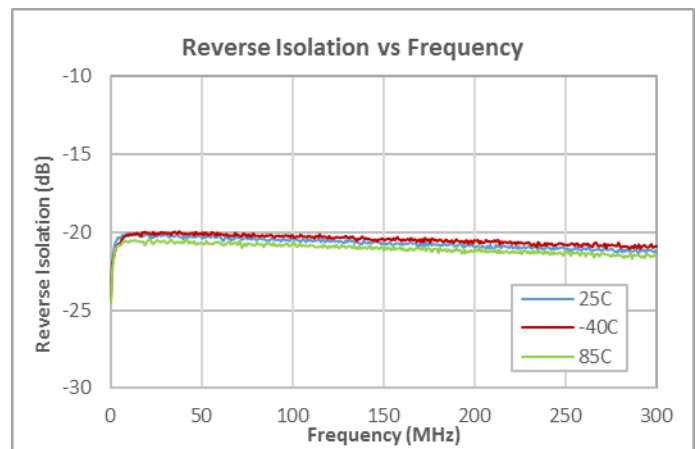
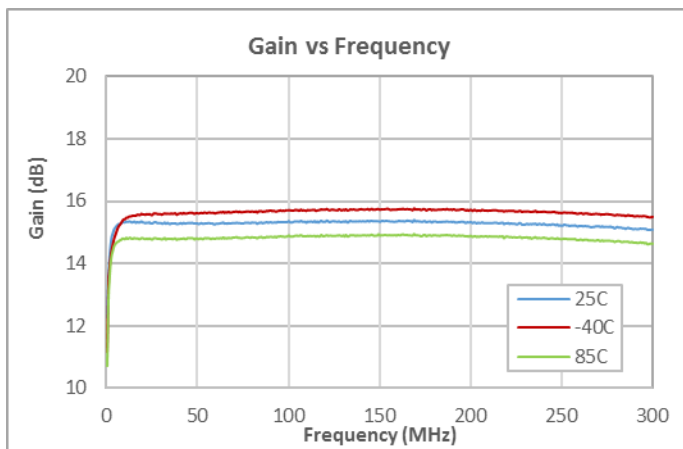
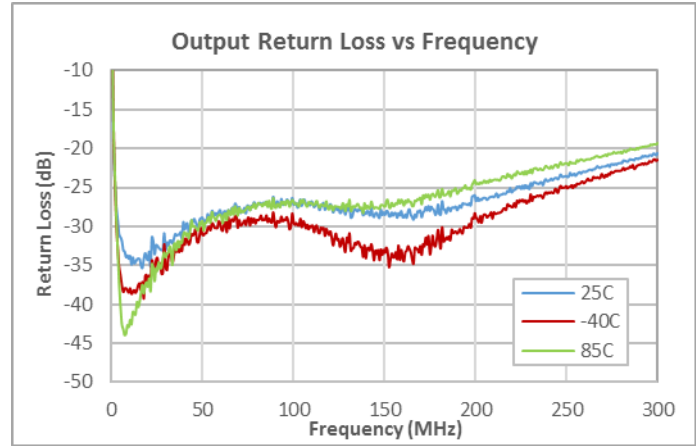
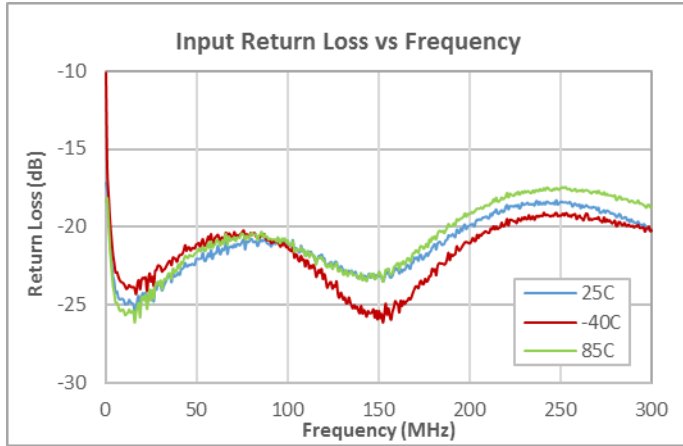


- Notes:
- (2) OIP2: 12dBm/tone, F1 = 113MHz, F2 = 119MHz
 - (3) DSO/DTO: f1=13MHz, f2=19MHz 61dBmV per tone
 - (4) ACLR: Pout = 64dBmV, 5-195MHz OFDM w/ 9.6MHz exclusion band.

Performance Data – Push-Pull Configuration, 8V

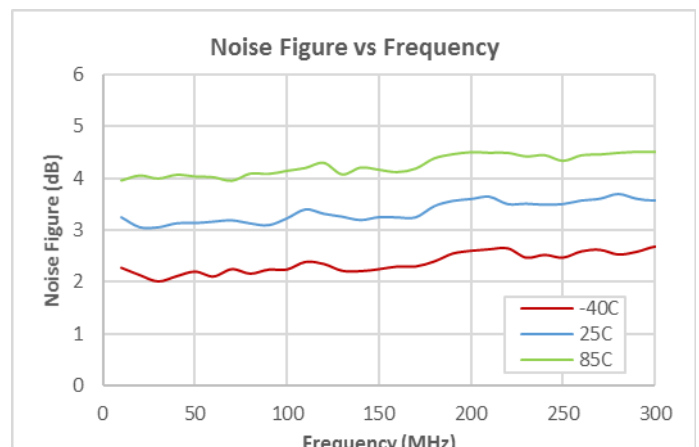
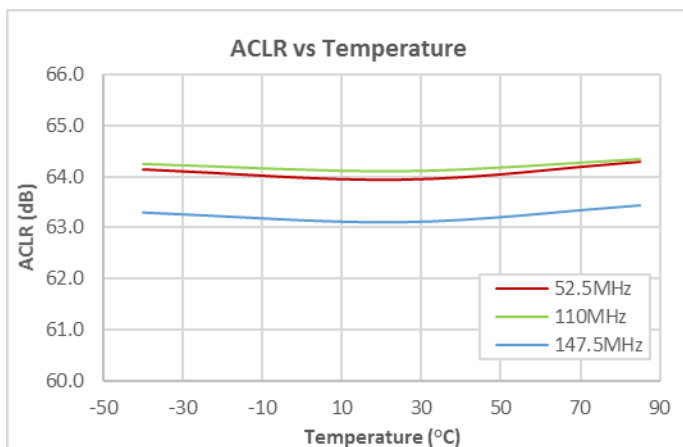
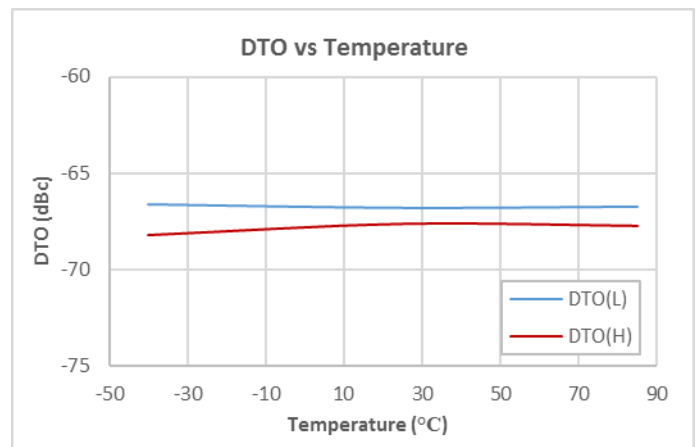
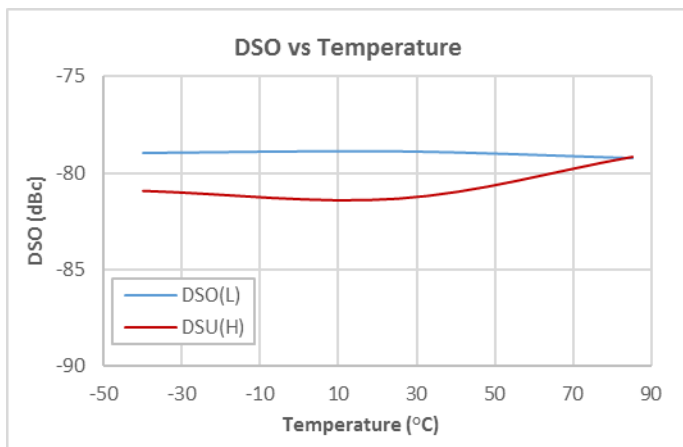
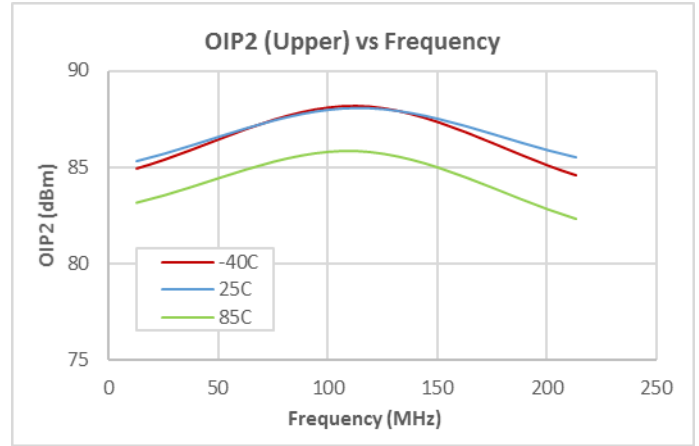
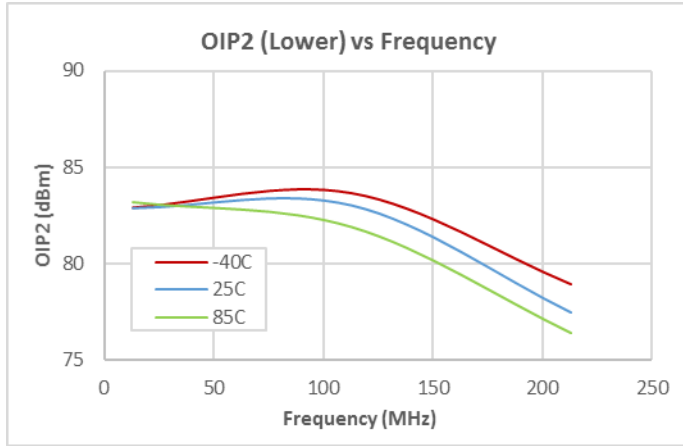


Performance Data – Push-Pull Configuration, 5V



Notes:
 (1) OIP3: 4dBm/tone, F1 = 113MHz, F2 = 119MHz

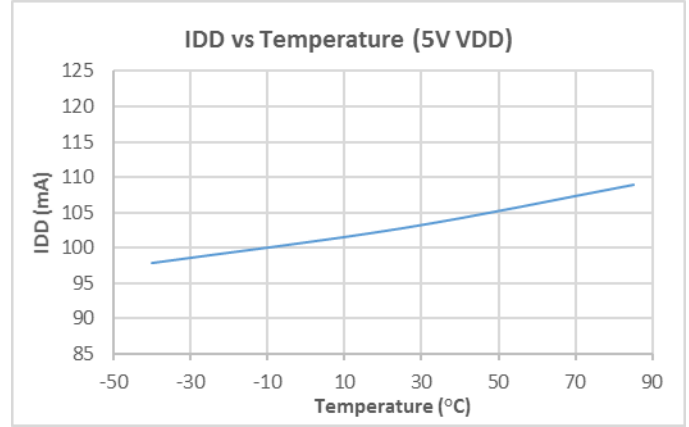
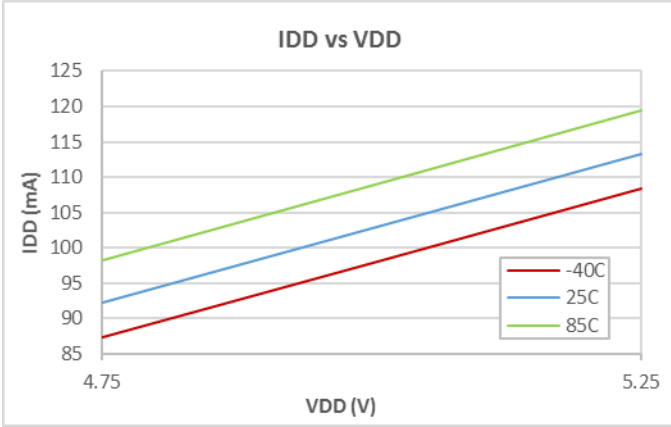
Performance Data – Push-Pull Configuration, 5V



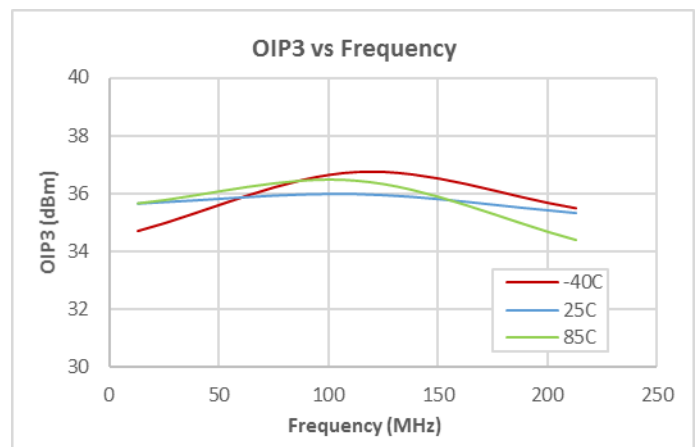
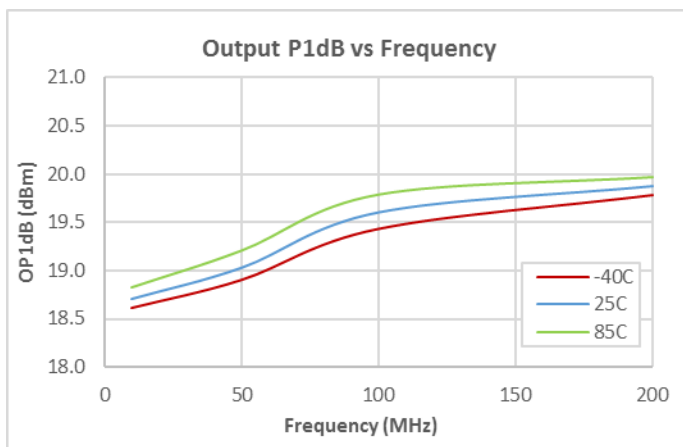
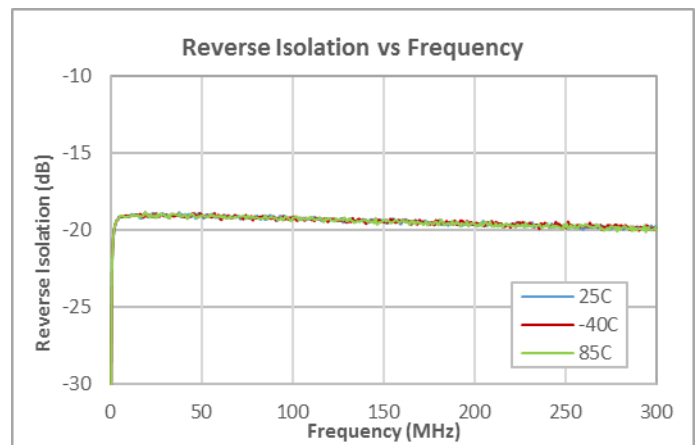
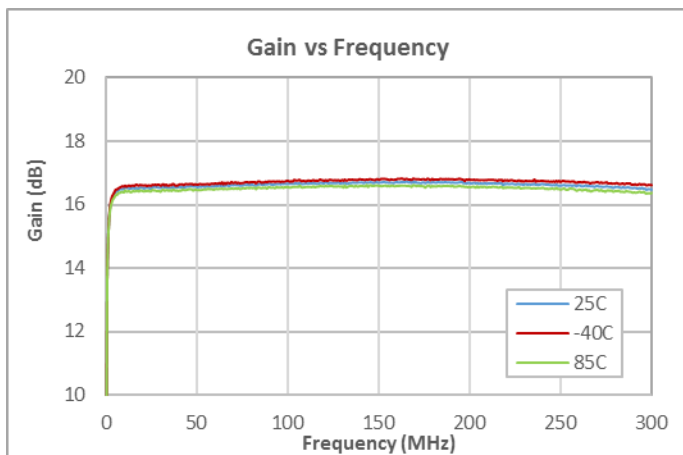
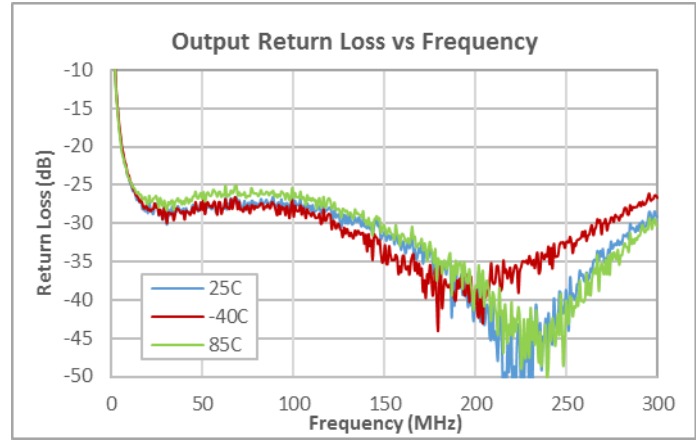
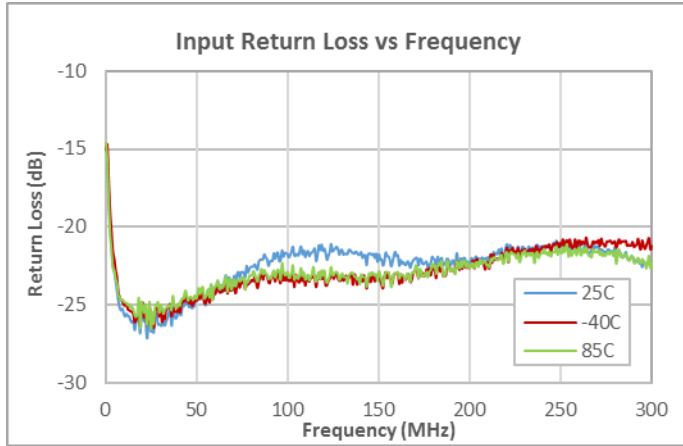
Notes:

- (1) OIP2: 4dBm/tone, F1 = 113MHz, F2 = 119MHz
- (2) DSO/DTO: f1=13MHz, f2=19MHz 53dBmV per tone
- (3) ACLR: Pout = 56dBmV, 5-195MHz OFDM w/ 9.6MHz exclusion band.

Performance Data – Push-Pull Configuration, 5V



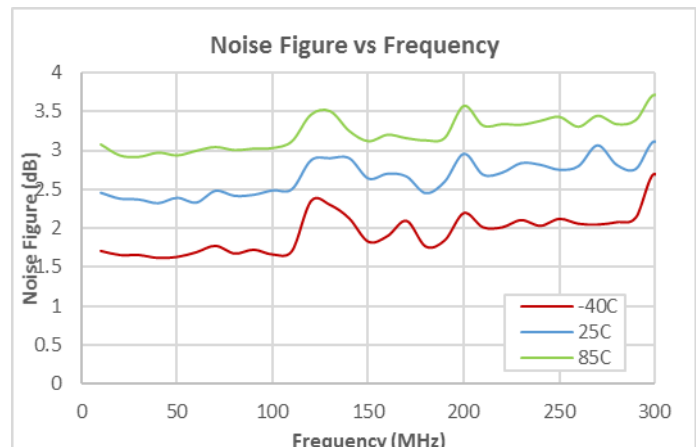
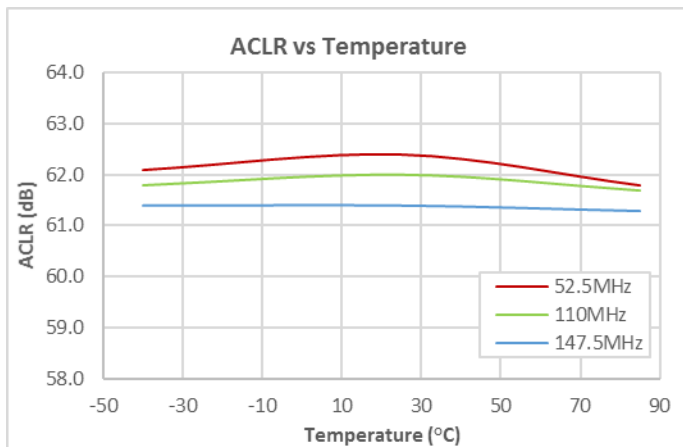
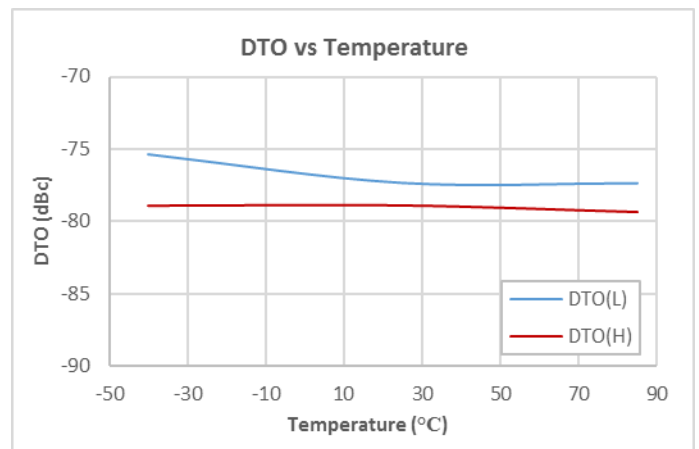
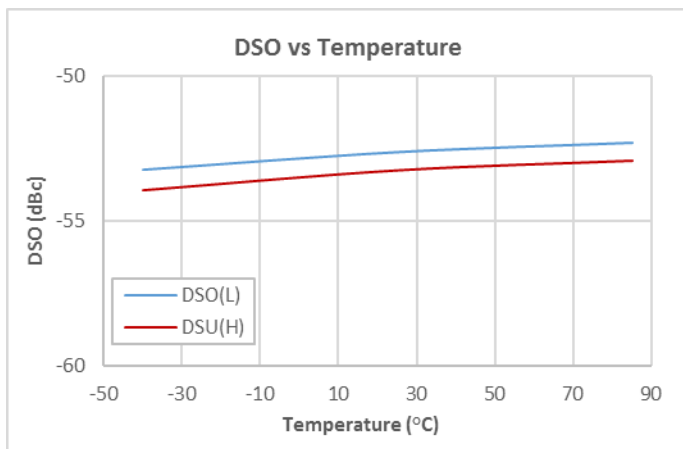
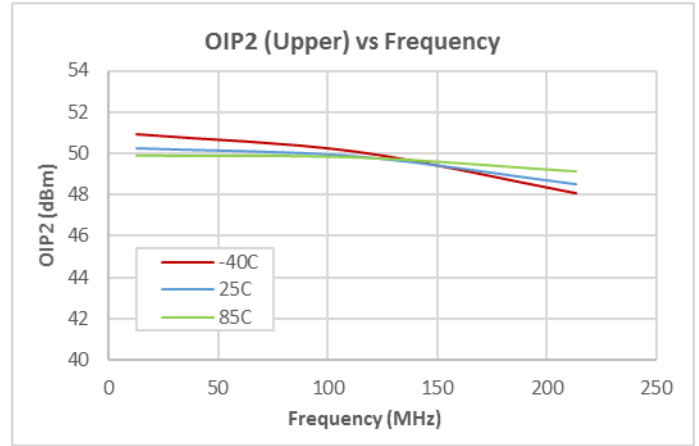
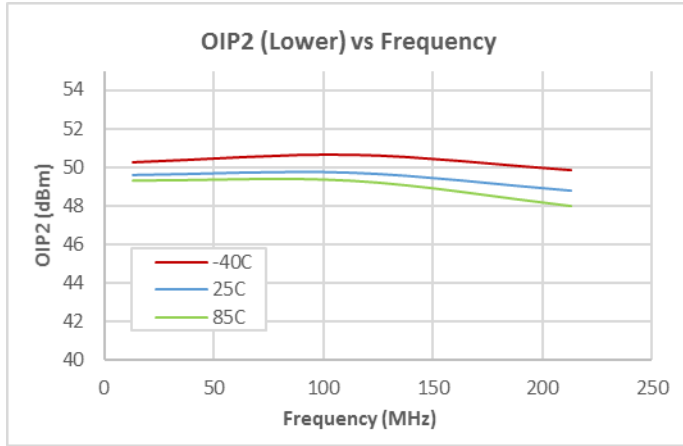
Performance Data – Single Ended Configuration, 5V



Notes:

- (1) OIP3: -3dBm/tone, F1 = 113MHz, F2 = 119MHz

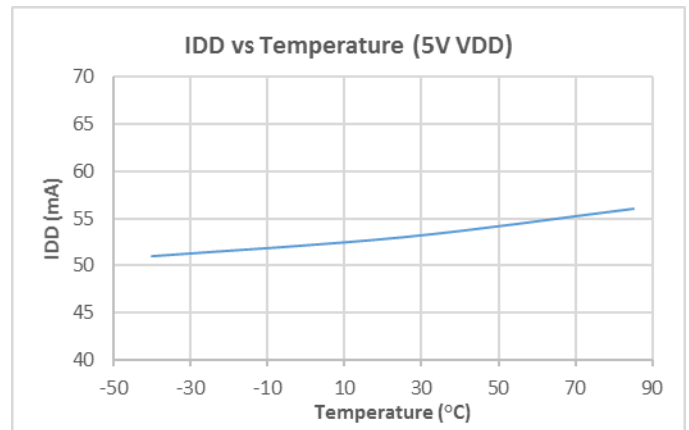
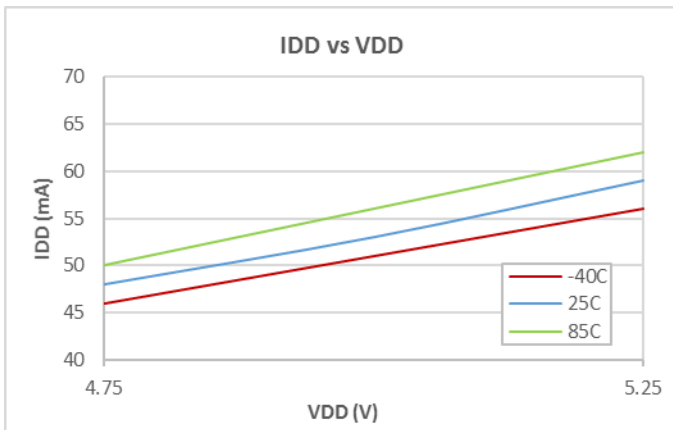
Performance Data – Single Ended Configuration, 5V



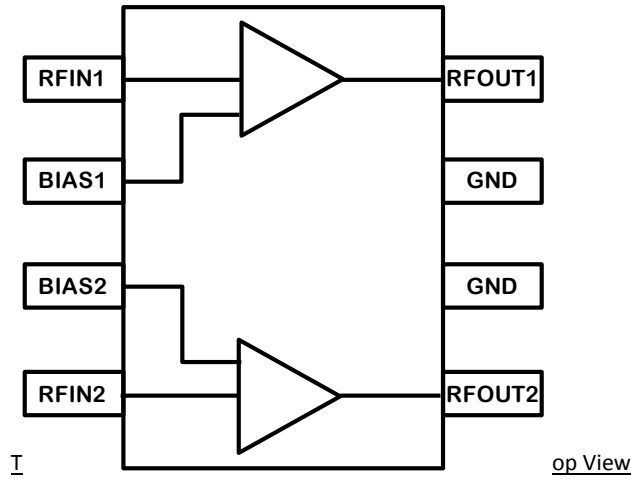
Notes:

- (1) OIP2: -3dBm/tone, F1 = 113MHz, F2 = 119MHz
- (2) DSO/DTO: f1=13MHz, f2=19MHz 46dBmV per tone
- (3) ACLR: Pout = 49dBmV, 5-195MHz OFDM w/ 9.6MHz exclusion band.

Performance Data – Single Ended Configuration, 5V

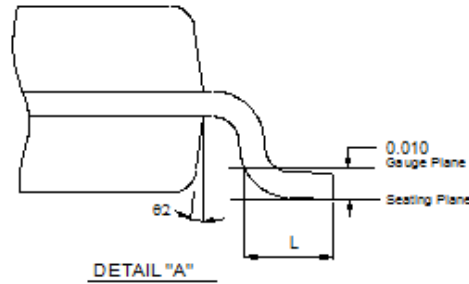
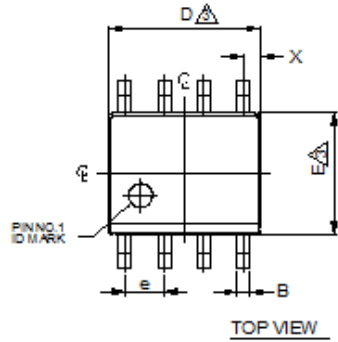


Pad Configuration and Description

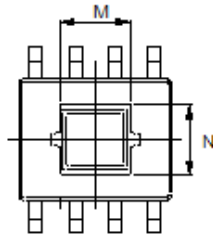
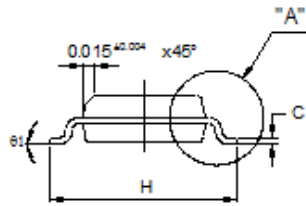
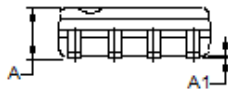


Pad No.	Label	Description
1	RFIN1	RF Input for AMP1
2	BIAS1	AMP1 bias, requires choke to ground
3	BIAS2	AMP2 bias, requires choke to ground
4	RFIN2	RF Input for AMP2
5	RFOUT2	RF Output for AMP2
6	GND	Internally Not Connected
7	GND	Internally Not Connected
8	RFOUT1	RF Output for AMP1
Backside Paddle	GND	Ground. Use recommended via pattern to minimize inductance and thermal resistance. See PCB Mounting Pattern for suggested footprint.

Package Outline



SYMBOL	8 SOIC	
	MIN	MAX
A	0.054	0.068
A1	0.001	0.004
B	0.014	0.019
D	0.189	0.196
E	0.150	0.157
H	0.229	0.244
M	0.087	0.097
N	0.082	0.092
e	0.050 BSC	
C	0.0075	0.0098
L	0.020	0.040
X	0.0215 REF	
61	0°	8°
62	7° BSC	



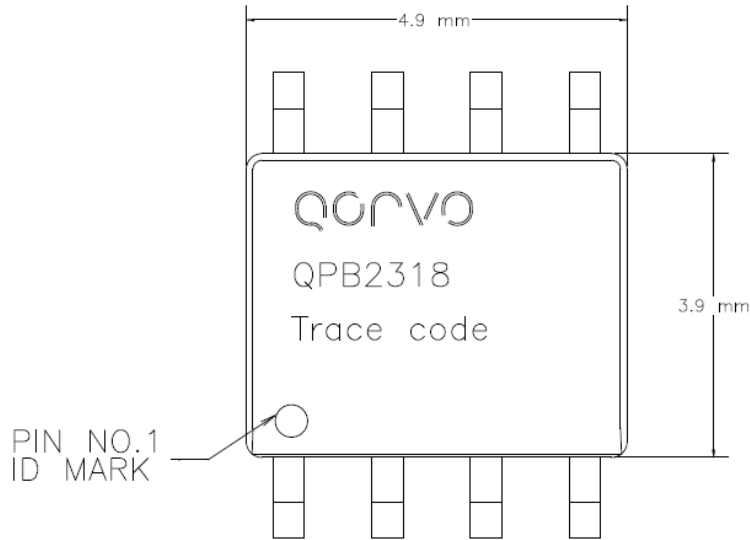
EXPOSED PADDLE

- NOTE:
1. TOP PACKAGE SURFACE TO BE Ni, Pd, Au PLATING
 2. BOTTOM PACKAGE SURFACE TO BE Ni, Pd, Au PLATING
 3. DIMENSIONS ARE EXCLUSIVE MOLD FLASH AND GATE BURR.
 4. FOOT LENGTH MEASURING IS BASED ON THE GAUGE PLANE METHOD.

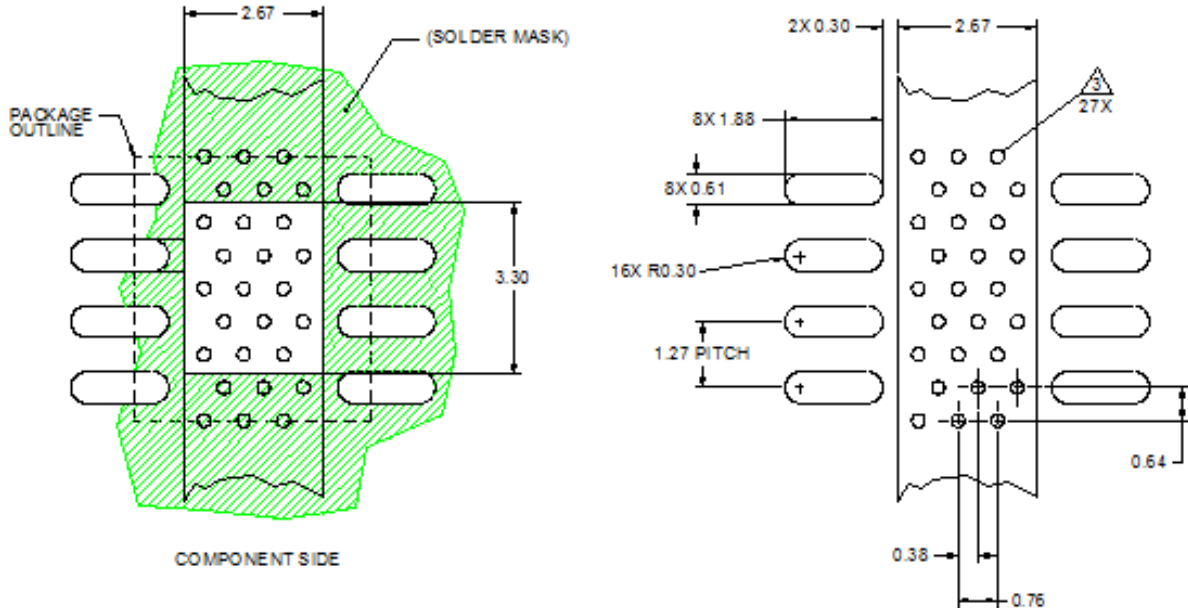
Notes:

1. Dimensions in millimeters

Package Marking



Recommended Mounting Pattern



Notes:

1. All dimensions are in millimeters. Angles are in degrees.
2. Use 1oz. copper minimum for top and bottom layers
3. Vias are required under the backside paddle for proper RF/DC grounding and thermal dissipation. We recommend a 0.35mm (#80/0.135") diameter bit for drilling via holes and a final plated through diameter of 0.25mm (0.010").
4. Ensure good backside paddle solder attach for reliable operation and best electrical performance.